

To compute  $sp$  we assume  $V(\vec{r})$  is slowly varying so that the system is in local equilibrium at every position  $\vec{r}$ . This approx is good for getting the small  $\hbar$  limit of  $\epsilon(\hbar)$ .

Then the probability to have an electron with wave vector  $\vec{k}$  at position  $\vec{r}$  is given by the Fermi function

$$f(\vec{k}, \vec{r}) = \frac{1}{e^{(\epsilon_{\vec{k}} - eV^{tot}(\vec{r}) - \mu)/k_B T} + 1}$$

$$= f^0(\vec{k}; \mu + eV^{tot}(\vec{r}))$$

where  $f^0(\vec{k}; \mu) = \frac{1}{e^{(\epsilon_{\vec{k}} - \mu)/k_B T} + 1}$  is the equilibrium distribution when  $V=0$ .

So the effect of  $V^{tot}(\vec{r})$  can be viewed as if there is now a spatially varying chemical potential  $\mu + eV^{tot}(\vec{r})$  (this is sometimes called the electro-chemical potential)

Then

$$sp(\vec{r}) = -e \int \frac{d^3k}{4\pi^3} \left[ f^0(\vec{k}; \mu + eV^{tot}(\vec{r})) - f^0(\vec{k}; \mu) \right]$$

↑

includes factor

$\times 2$  for spin degeneracy

expand in small  $eV^{\text{tot}} \ll \mu \approx \epsilon_F$

$$\begin{aligned}\delta p(\vec{r}) &= -e \int \frac{d^3k}{4\pi^3} \frac{\partial f^0}{\partial \mu} eV^{\text{tot}}(\vec{r}) \\ &= -e^2 V^{\text{tot}}(\vec{r}) \frac{\partial}{\partial \mu} \int \frac{d^3k}{4\pi^3} f^0(\vec{k})\end{aligned}$$

$$= -e^2 V^{\text{tot}}(\vec{r}) \frac{\partial n}{\partial \mu}$$

equilibrium density  $n(\mu)$  as function of chemical pot  $\mu$ .

~~$\frac{\delta p(\vec{r})}{V^{\text{tot}}(\vec{r})}$~~

So also  $\delta p(\vec{k}) = -e^2 V^{\text{tot}}(\vec{k}) \frac{\partial n}{\partial \mu}$

$$\frac{\delta p(\vec{k})}{V^{\text{tot}}(\vec{k})} = -e^2 \left( \frac{\partial n}{\partial \mu} \right)$$

So dielectric function is

$$\epsilon(\vec{k}) = 1 - \frac{4\pi}{k^2} \frac{\delta p(\vec{k})}{V^{\text{tot}}(\vec{k})}$$

$$\epsilon(\vec{k}) = 1 + \frac{4\pi e^2}{k^2} \frac{\partial n}{\partial \mu}$$

This is called the Thomas-Fermi dielectric function, and it can be written in the form

$$\epsilon(\vec{k}) = 1 + k_0^2/k^2 \quad k_0^2 \equiv 4\pi e^2 \frac{\partial n}{\partial \mu}$$

where  $1/k_0$  is called the screening length

Before considering the physical consequences of  $\epsilon(\vec{k})$  as above, let's first compute  $k_0$ .

As  $T \rightarrow 0$ ,  $\mu \rightarrow \epsilon_F$  the Fermi energy. Now  $\epsilon_F$  is defined by

$$M = \int_0^{\epsilon_F} d\epsilon g(\epsilon) \Rightarrow \frac{\partial M}{\partial \epsilon_F} = g(\epsilon_F)$$

↑  
density of states

For a free electron gas,  $g(\epsilon_F) = \frac{3}{2} \frac{M}{\epsilon_F}$

$$\text{So } k_0^2 = 4\pi e^2 g(\epsilon_F) = \frac{6\pi e^2 M}{\epsilon_F}$$

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We can compare this to what one would get using classical Boltzmann statistics for the electrons, instead of the quantum Fermi-Dirac statistics. Then, the probability distribution for an electron with momentum  $\hbar\vec{k}$  would be

$$f(\vec{k}, \vec{r}) = C e^{-\frac{(\epsilon_k - eV^{\text{tot}}(\vec{r}))}{k_B T}}$$

↑  
normalization constant

expand for small  $eV^{\text{tot}}$

$$f(\vec{k}, \vec{r}) \approx c e^{-\epsilon_k/k_B T} \left[ 1 + \frac{eV^{\text{tot}}(\vec{r})}{k_B T} \right]$$
$$= f^0(k) \left[ 1 + \frac{eV^{\text{tot}}(\vec{r})}{k_B T} \right]$$

$$S_f(\vec{r}) = -e \int \frac{d^3k}{4\pi^3} \left[ f(\vec{k}, \vec{r}) - f^0(k) \right]$$
$$= -e \int \frac{d^3k}{4\pi^3} f^0(k) \frac{eV^{\text{tot}}(\vec{r})}{k_B T}$$
$$= -e^2 V^{\text{tot}}(\vec{r}) \frac{m}{k_B T}$$

So  $\frac{S_f(\vec{r})}{V^{\text{tot}}(\vec{r})} = -\frac{e^2 m}{k_B T}$  which gives

$$\epsilon(\vec{k}) = 1 - \frac{4\pi}{k^2} \frac{S_f(\vec{k})}{V^{\text{tot}}(\vec{k})} = 1 + \frac{4\pi e^2 m}{k^2 k_B T}$$

This is known as the Debye-Hückel dielectric function - it applies to a liquid or gas of charged particles obeying classical statistics (for example is  $T \gg T_F$ ). It has the same function form as the Thomas-Fermi dielectric function, but now with

$$k_0^2 = \frac{4\pi e^2 m}{k_B T}$$

So to compare Thomas - Fermi with classical Debye - Hückel

$$\frac{k_0^{TF}}{k_0^{DH}} = \left( \frac{6\pi e^2 m}{k_B T_F} \frac{k_B T}{4\pi e^2 m} \right)^{1/2} = \left( \frac{3}{2} \left( \frac{T}{T_F} \right) \right)^{1/2} \ll 1$$

so Debye Hückel screening length  $\frac{1}{k_0^{DH}} \ll \frac{1}{k_0^{TF}}$  Thomas-Fermi screening lengths, for the same density  $n$ .

Back to Thomas - Fermi

$$k_0^2 = \frac{6\pi e^2 m}{E_F} \quad \text{using } m = \frac{k_F^3}{3\pi^2}, \quad E_F = \frac{\hbar^2 k_F^2}{2m}$$

$$\Rightarrow k_0^2 = \frac{4me^2}{\pi\hbar^2} k_F \quad \text{using Bohr radius } a_0 = \frac{\hbar^2}{me^2}$$

$$\Rightarrow k_0^2 = \frac{4}{\pi} k_F / a_0 \quad \text{using } \frac{4}{3}\pi r_s^3 = \frac{1}{n}$$

$$k_F = \left( \frac{9\pi}{4} \right)^{1/3} \frac{1}{r_s}$$

$$\Rightarrow k_0 = \sqrt{\frac{4}{\pi} \left( \frac{9\pi}{4} \right)^{1/3}} \frac{1}{\sqrt{r_s a_0}}$$

$$\frac{1.56}{\sqrt{r_s a_0}} = 1.56$$

$$\frac{1}{a_0 k_0} = \frac{1}{1.56} \sqrt{\frac{r_s}{a_0}}$$

$r_s \sim 3a_0$  for most metals

$\Rightarrow \frac{1}{k_0} \sim a_0 \sim 0.5 \text{ \AA}$  screening length very small!

## Thomas-Fermi dielectric function

$$\epsilon(k) = 1 + k_0^2/k^2, \quad \text{with } 1/k_0 \sim \text{\AA}$$

One consequence of this form is something you have already learned in your EM class.

If we take the limit  $k \rightarrow 0$ , then  $\epsilon \rightarrow \infty$ .

So a uniform electric field applied to a metal is completely screened out!  $E^{\text{tot}} = \frac{E}{\epsilon} \rightarrow 0$ .

In practice, provided the applied  $E$  field is slowly varying on the length scale  $1/k_0 \sim \text{\AA}$ , it is still screened out because  $\epsilon$  is so large for  $k \ll k_0$ . This is what you learned in EM

- there can be no static macroscopic electric field inside a metal.

Another extremely important consequence of the T-F dielectric function is seen if we consider the effect on a point charge  $Q$  placed in the electron gas.

The "applied" potential ~~of the~~ from the point charge is just the bare Coulomb potential

$$V(\vec{r}) = \frac{Q}{r}$$

The Fourier transform of the Coulomb potential is

$$V(\vec{k}) = \frac{4\pi Q}{k^2}$$

$$\begin{aligned}\Rightarrow V^{\text{tot}}(\vec{k}) &= \frac{V(\vec{k})}{\epsilon(\vec{k})} = \frac{4\pi Q}{k^2} \frac{1}{1 + k_0^2/k^2} \\ &= \frac{4\pi Q}{k_0^2 + k^2}\end{aligned}$$

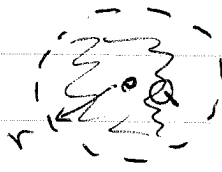
whereas  $V(\vec{k}) \rightarrow \infty$  as  $k \rightarrow 0$ , indicating a long ranged interaction,  $V^{\text{tot}}(\vec{k}) \rightarrow \text{const}$  as  $k \rightarrow \infty$ , indicating a short ranged interaction.

If we Fourier transform  $V^{\text{tot}}(\vec{k})$  back to real space we get the interaction

$$V^{\text{tot}}(\vec{r}) = \frac{Qe^{-k_0 r}}{r} \quad \text{called the "Yukawa potential" or the "screened Coulomb potential"}$$

The effect of the dielectric function due to the free electrons is to "screen" the long range Coulomb-potential so it looks short ranged with an interaction length  $= 1/k_0$ . On length scales  $r \gg 1/k_0$ , the effect of the charge  $Q$  is entirely negligible. We say that the electrons have screened out the charge  $Q$ .

Physically, what is going on is as follows:



electrons get attracted to charge  $Q$  and so the average electron density about  $Q$  increases above average. This cloud of electron charge at  $Q$  "screens" the charge  $Q$ . If one computes the total charge (i.e.  $Q$  + induced electron charge) in a sphere of radius  $r$  centered on  $Q$ , this total charge decreases to zero as  $r \rightarrow \infty$ . Decay of this total charge is on length scale  $1/k_0$ .

Compare this to behavior in a "dielectric" (i.e. an insulator) from EM class. If you put a point charge  $Q$  in a dielectric, it polarizes the material creating bound charges at  $Q$  so that the total charge at  $Q$  becomes  $Q + Q_{\text{bound}} = Q/\epsilon$ , where  $\epsilon$  is the finite "dielectric constant". A metal is like a dielectric with an infinite dielectric constant so that  $Q/\epsilon \rightarrow 0$ ! (any free charge in a metal must lie on its surface!). The dependence of  $\epsilon$  on wavevector  $k$ , describes how the metal screens charges on finite length scales - so  $Q/\epsilon \rightarrow 0$  is really just a statement about the  $r \rightarrow \infty$ , or  $k \rightarrow 0$  limit, of the metal.



about the screening of <sup>the</sup> electron-electron interaction, since all electrons are identical, we cannot really distinguish between a given pair of interacting electrons and the other electrons that are screening this interaction. But despite this complication, the idea that  $\epsilon(k)$  ~~screen~~ screens the e-e interaction and makes it short ranged, remains essentially correct. See Ashcroft + Mermin Chpt 17 or Kittel Chpt 14 for further discussion.